

## Refine Search

### Search Results -

Terms	Documents
L11 and (nitride near8 (aperture or hole or via or opening)).clm.	2

**Database:** US Pre-Grant Publication Full-Text Database  
 US Patents Full-Text Database  
 US OCR Full-Text Database  
 EPO Abstracts Database  
 JPO Abstracts Database  
 Derwent World Patents Index  
 IBM Technical Disclosure Bulletins

**Search:** L13

### Search History

**DATE:** Thursday, May 18, 2006 [Printable Copy](#) [Create Case](#)

<u>Set</u>	<u>Name</u>	<u>Query</u>	<u>Hit</u>	<u>Set</u>
			<u>Count</u>	<u>Name</u>
side by side				result set
DB=PGPB,USPT,USOC,EPAB,JPAB,DWPI,TDBD; PLUR=YES; OP=ADJ				
<u>L13</u>	L11 and (nitride near8 (aperture or hole or via or opening)).clm.		2	<u>L13</u>
<u>L12</u>	L11 and (nitride near8 (aperture or hole or via or opening))		4	<u>L12</u>
<u>L11</u>	L2 and (first near2 electrode same nitride same second near2 electrode)		31	<u>L11</u>
<u>L10</u>	L9 and (nitride near8 electrode)		11	<u>L10</u>
<u>L9</u>	L8 and L1		66	<u>L9</u>
<u>L8</u>	"Tomohiko".inv.		12525	<u>L8</u>
<u>L7</u>	L6 and L1		0	<u>L7</u>
<u>L6</u>	"Takumori".inv.		70	<u>L6</u>
<u>L5</u>	"Takumori" near3 "Iki"		0	<u>L5</u>
<u>L4</u>	Takumori near3 Iki		0	<u>L4</u>
<u>L3</u>	L2 and (nitride near8 (aperture or hole or via or opening))		59	<u>L3</u>
<u>L2</u>	L1 and (electrode near7 (top or above or bottom or underneath or over near8 nitride))		265	<u>L2</u>

L1 ((thin film transistor)or TFT) same capacit\$

18922 L1

END OF SEARCH HISTORY